P-Channel Enhancement-Mode Vertical DMOS FET

Features

- Free from secondary breakdown
- Low power drive requirement
- Ease of paralleling
- Low C_{ISS} and fast switching speeds
- High input impedance and high gain
- Excellent thermal stability
- Integral source-to-drain diode

Applications

- Motor controls
- Converters
- Amplifiers
- Switches
- Power supply circuits
- Drivers (relays, hammers, solenoids, lamps, memories, displays, bipolar transistors, etc.)

General Description

The Supertex VP2450 is an enhancement-mode (normally-off) transistor that utilizes a vertical DMOS structure and Supertex's well-proven silicon-gate manufacturing process. This combination produces a device with the power handling capabilities of bipolar transistors, and the high input impedance and positive temperature coefficient inherent in MOS devices. Characteristic of all MOS structures, this device is free from thermal runaway and thermally-induced secondary breakdown.

Supertex's vertical DMOS FETs are ideally suited to a wide range of switching and amplifying applications where very low threshold voltage, high breakdown voltage, high input impedance, low input capacitance, and fast switching speeds are desired.

Ordering Information

Device	Package Options		BV_{DSS}/BV_{DGS} (V)	$R_{DS(ON)}$ (max) (Ω)	$I_{D(ON)}$ (min) (mA)
	TO-92	TO-243AA (SOT-89)			
VP2450	VP2450N3-G	VP2450N8-G	-500	30	-200

-G indicates package is RoHS compliant ('Green')

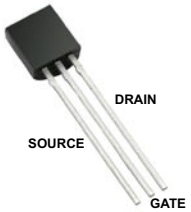
Absolute Maximum Ratings

Parameter	Value
Drain-to-Source voltage	BV_{DSS}
Drain-to-Gate voltage	BV_{DGS}
Gate-to-Source voltage	±20V
Operating and storage temperature	-55°C to +150°C
Soldering temperature*	300°C

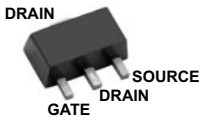
Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. Continuous operation of the device at the absolute rating level may affect device reliability. All voltages are referenced to device ground.

* *Distance of 1.6mm from case for 10 seconds.*

Pin Configurations



TO-92 (N3)



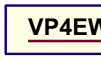
TO-243AA (SOT-89) (N8)

Product Marking

YY = Year Sealed
WW = Week Sealed
_____ = "Green" Packaging

Package may or may not include the following marks: Si or

TO-92 (N3)



W = Code for week sealed
_____ = "Green" Packaging

Packages may or may not include the following marks: Si or

TO-243AA (SOT-89) (N8)

Thermal Characteristics

Package	I_D (continuous)† (mA)	I_D (pulsed) (mA)	Power Dissipation @T_c = 25°C (W)	θ_{jc} (°C/W)	θ_{ja} (°C/W)	I_{DR}† (mA)	I_{DRM} (mA)
TO-92	-100	-300	1.0	125	170	-100	-300
TO-243AA (SOT-89)	-160	-800	1.6‡	15	78	-160	-800

† I_D (continuous) is limited by max rated T_j.
‡ Mounted on FR5 board, 25mm x 25mm x 1.57mm.

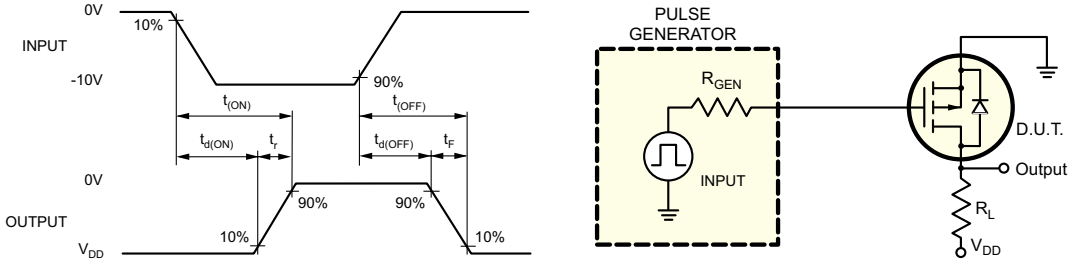
Electrical Characteristics (T_A = 25°C unless otherwise specified)

Sym	Parameter	Min	Typ	Max	Units	Conditions
BV_{DSS}	Drain-to-source breakdown voltage	-500	-	-	V	V_{GS} = 0V, I_D = -250µA
$V_{GS(th)}$	Gate threshold voltage	-1.5	-	-3.5	V	V_{GS} = V_{DS}, I_D= -1.0mA
$\Delta V_{GS(th)}$	Change in $V_{GS(th)}$ with temperature	-	-	-4.8	mV/°C	V_{GS} = V_{DS}, I_D= -1.0mA
I_{GSS}	Gate body leakage	-	-	-100	nA	V_{GS} = ± 20V, V_{DS} = 0V
I_{DSS}	Zero gate voltage drain current	-	-	-10	µA	V_{GS} = 0V, V_{DS} = Max Rating
		-	-	-1.0	mA	V_{DS} = 0.8 Max Rating, V_{GS} = 0V, T_A = 125°C
$I_{D(ON)}$	On-state drain current	-75	-	-	mA	V_{GS} = -4.5V, V_{DS} = -15V
		-200	-	-		V_{GS} = -10V, V_{DS} = -15V
$R_{DS(ON)}$	Static drain-to-source on-state resistance	-	-	35	Ω	V_{GS} = -4.5V, I_D = -50mA
		-	-	30		V_{GS} = -10V, I_D = -100mA
$\Delta R_{DS(ON)}$	Change in $R_{DS(ON)}$ with temperature	-	-	0.75	%/°C	V_{GS} = -10V, I_D = -100mA
G_{FS}	Forward transductance	150	320	-	mmho	V_{DS} = -15V, I_D = -100mA
C_{ISS}	Input capacitance	-	-	190	pF	V_{GS} = 0V, V_{DS} = -25V, f = 1.0MHz
C_{OSS}	Common source output capacitance	-	-	75		
C_{RSS}	Reverse transfer capacitance	-	-	20		
$t_{d(ON)}$	Turn-on delay time	-	-	10	ns	V_{DD} = -25V, I_D = -200mA, R_{GEN} = 25Ω
t_r	Rise time	-	-	25		
$t_{d(OFF)}$	Turn-off delay time	-	-	45		
t_f	Fall time	-	-	25		
V_{SD}	Diode forward voltage drop	-	-	-1.8	V	V_{GS} = 0V, I_{SD} = -100mA
t_{rr}	Reverse recovery time	-	300	-	ns	V_{GS} = 0V, I_{SD} = -100mA

Notes:

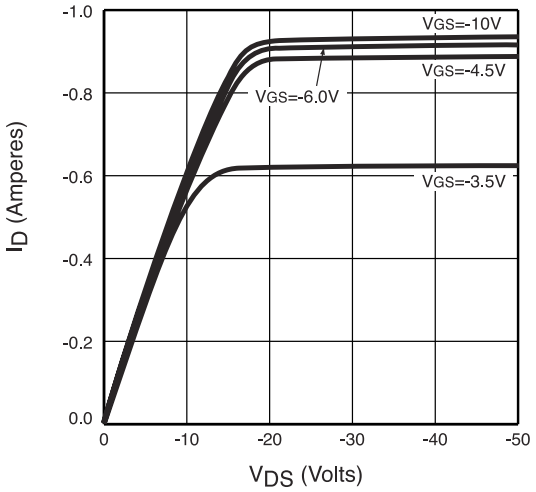
1. *All D.C. parameters 100% tested at 25°C unless otherwise stated. (Pulse test: 300µs pulse, 2% duty cycle.)*
2. *All A.C. parameters sample tested.*

Switching Waveforms and Test Circuit

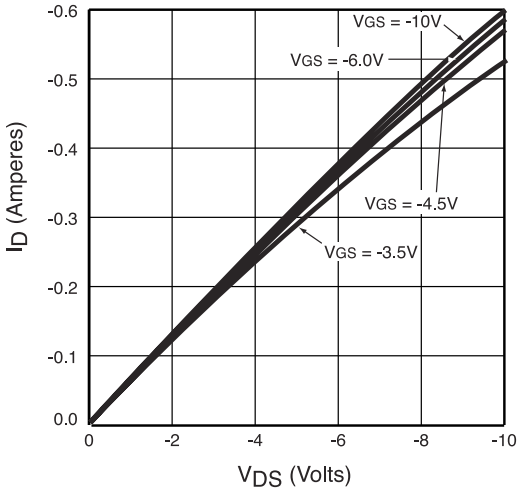


Typical Performance Curves

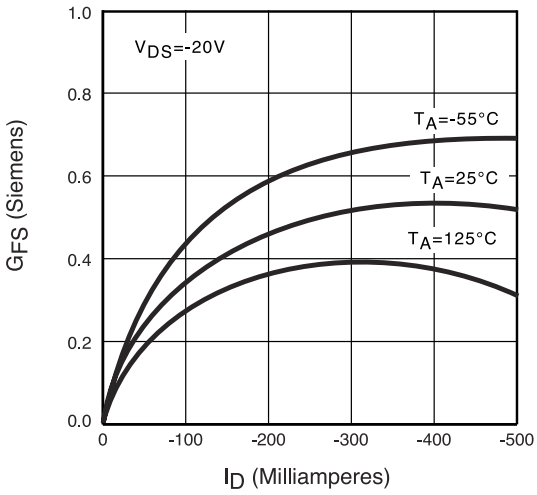
Output Characteristics



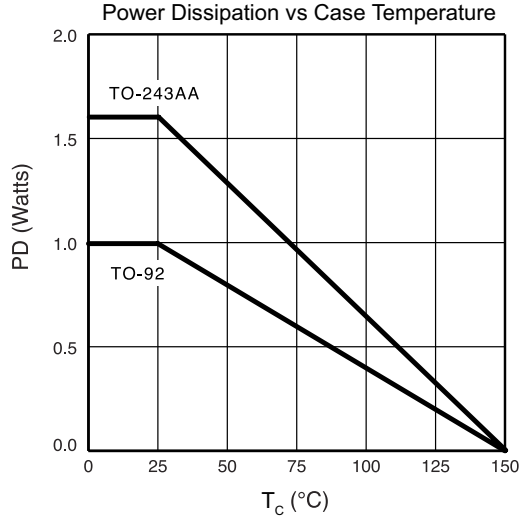
Saturation Characteristics



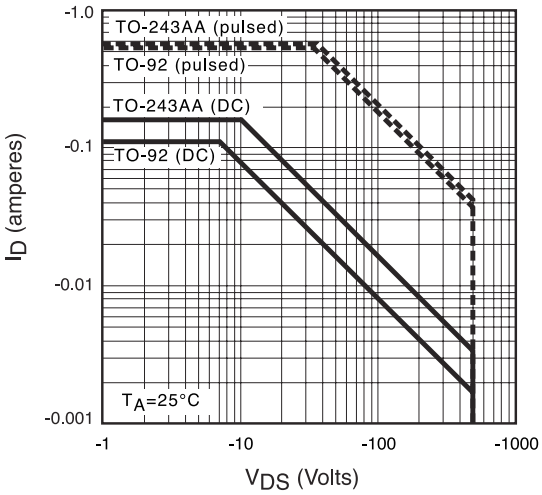
Transconductance vs. Drain Current



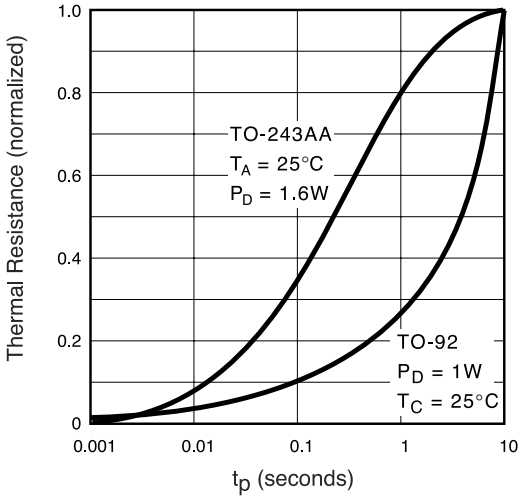
Power Dissipation vs Case Temperature



Maximum Rated Safe Operating Area

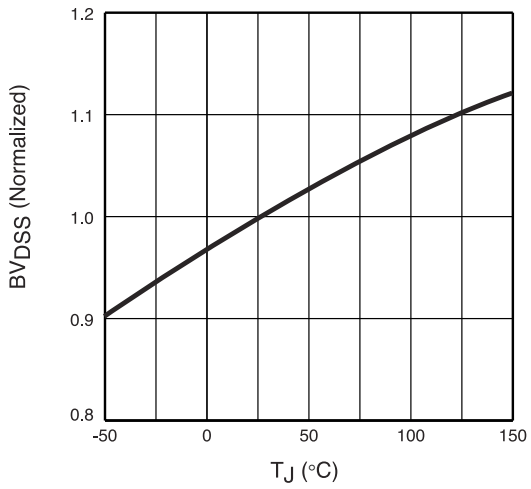


Thermal Response Characteristics

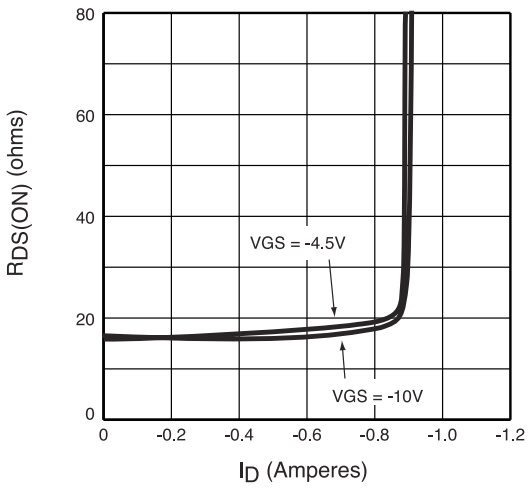


Typical Performance Curves *(cont.)*

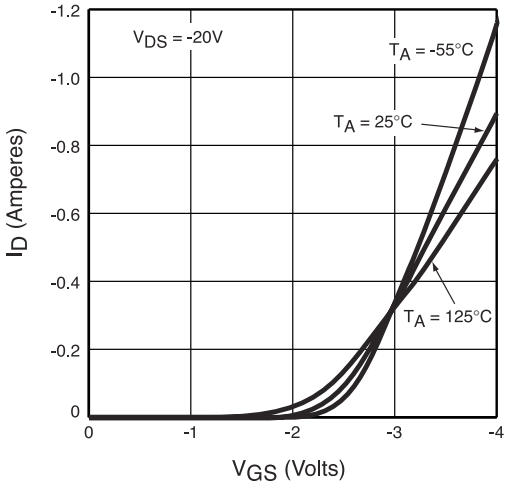
BVDSS Variation with Temperature



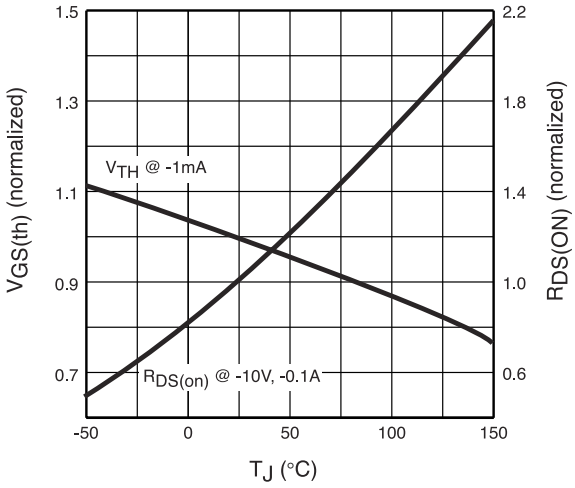
On Resistance vs. Drain Current



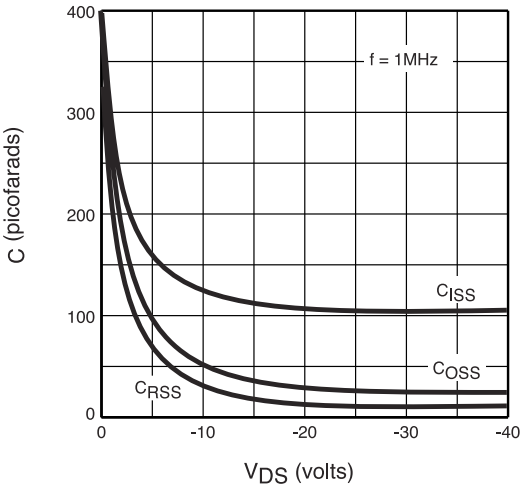
Transfer Characteristics



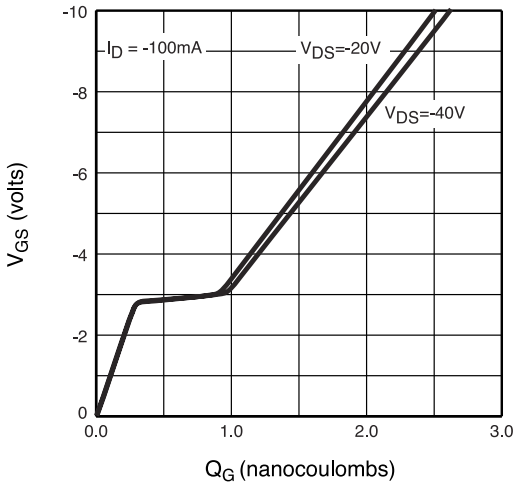
VGS(th) and RDS(on) Variation w/ Temperature



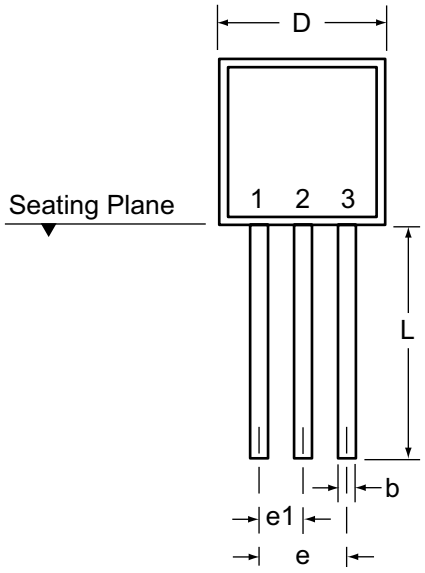
Capacitance vs. Drain Source Voltage



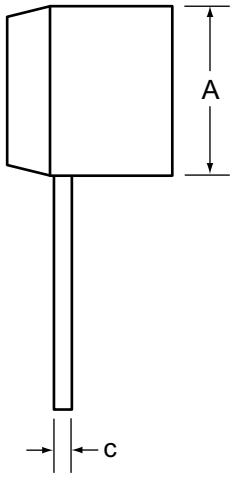
Gate Drive Dynamic Characteristics



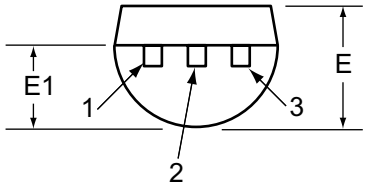
3-Lead TO-92 Package Outline (N3)



Front View



Side View

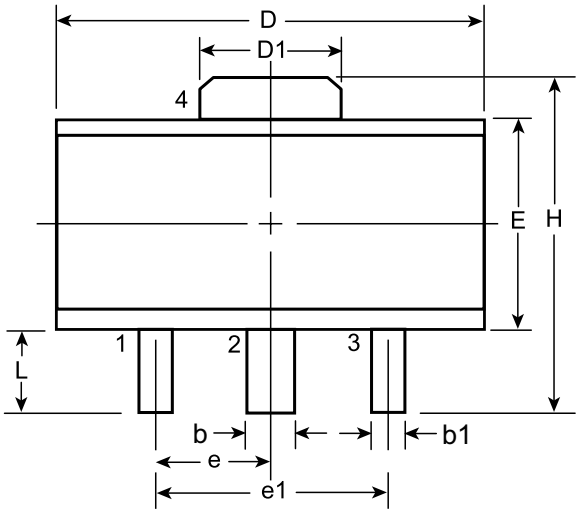


Bottom View

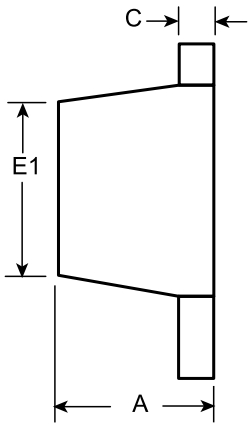
Symbol		A	b	c	D	E	E1	e	e1	L
Dimensions (inches)	MIN	.170	.014†	.014†	.175	.125	.080	.095	.045	.500
	NOM	-	-	-	-	-	-	-	-	-
	MAX	.210	.022†	.022†	.205	.165	.105	.105	.055	.610*

JEDEC Registration TO-92.
** This dimension is not specified in the original JEDEC drawing. The value listed is for reference only.*
† This dimension is a non-JEDEC dimension.
Drawings not to scale.
***Supertex Doc.#:** DSPD-3TO92N3, Version D080408.*

3-Lead TO-243AA (SOT-89) Package Outline (N8)



Top View



Side View

Symbol		A	b	b1	C	D	D1	E	E1	e	e1	H	L
Dimensions (mm)	MIN	1.40	0.44	0.36	0.35	4.40	1.62	2.29	2.13	1.50 BSC	3.00 BSC	3.94	0.89
	NOM	-	-	-	-	-	-	-	-			-	-
	MAX	1.60	0.56	0.48	0.44	4.60	1.83	2.60	2.29			4.25	1.20

JEDEC Registration TO-243, Variation AA, Issue C, July 1986.
Drawings not to scale.
Supertex Doc. #: *DSPD-3TO243AAN8, Version D070908.*

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to http://www.supertex.com/packaging.html.)

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